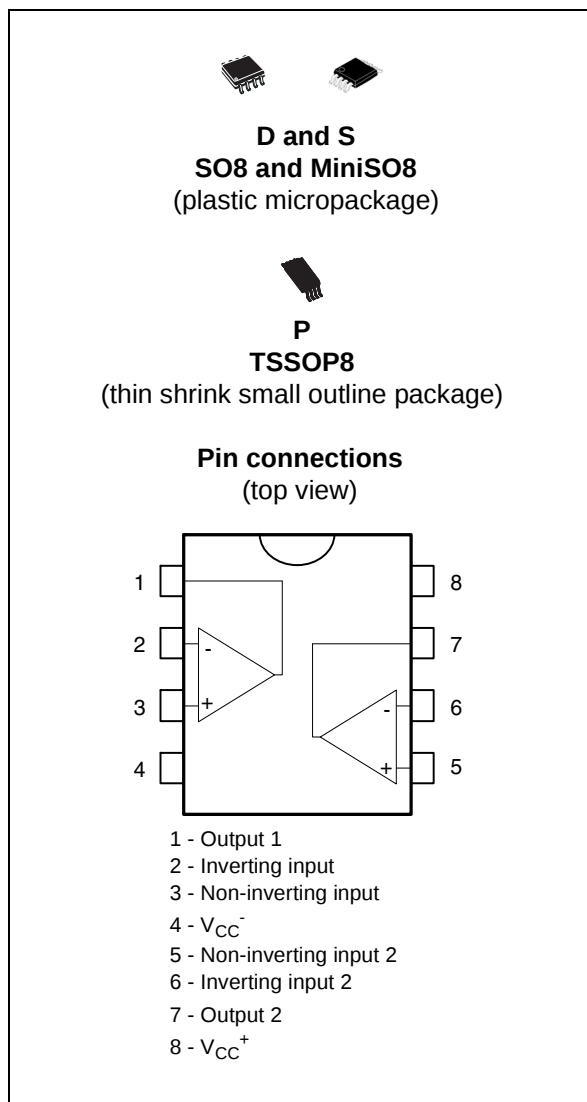




- Very low supply current per operator - essentially independent of supply voltage
- Low input bias current: 20 nA (temperature compensated)
- Low input offset voltage: 2 mV
- Low input offset current: 2 nA
- Input common mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0 V to (V_{CC}^+) - 1.5 V

Description

The LM158W, LM258W, and LM358W circuits consist of two independent, high-gain, operational amplifiers (op-amps), which employ an internal frequency compensation and are specifically designed to operate from a single power supply over a wide range of voltages. The low-power supply drain is independent of the power supply voltage magnitude. Application areas include transducer amplifiers, DC gain blocks, and all the conventional op-amp circuits, which can now be more easily implemented in single power supply systems. For example, these circuits can be directly supplied with the standard +5 V, which is used in logic systems and easily provide the required interface electronics with no additional power supply. In linear mode, the input common mode voltage range includes ground. The output voltage can also swing to ground, even though operated from a single power supply voltage.

Features

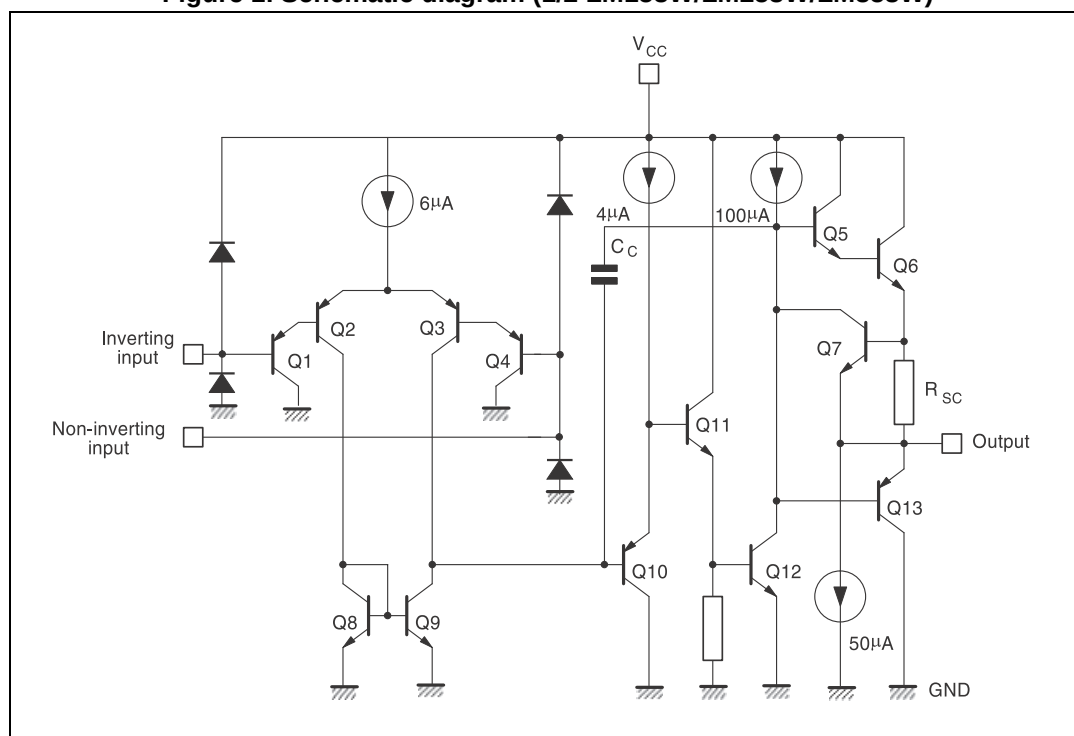
- ESD internal protection: 2 kV
- Internal frequency compensation implemented
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1.1 MHz (temperature compensated)

Contents

1	Schematic diagram	3
2	Absolute maximum ratings and operating conditions	4
3	Electrical characteristics	6
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1 Schematic diagram

Figure 1. Schematic diagram (1/2 LM158W/LM258W/LM358W)



2 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	LM158W/AW	LM258W/AW	LM358W/AW	Unit
V _{CC} ⁺	Supply voltage	+32			V
V _{in}	Input voltage	-0.3 to V _{CC} ⁺ +0.3			
V _{id}	Differential input voltage	-0.3 to V _{CC} ⁺ +0.3			
	Output short-circuit duration ⁽¹⁾	Infinite			
I _{in}	Input current ⁽²⁾	5 mA in DC or 50 mA in AC (duty cycle=10%, T=1 s)			mA
T _{oper}	Operating free-air temperature range	-55 to +125	-40 to +105	0 to +70	°C
T _{stg}	Storage temperature range	-65 to +150			
T _j	Maximum junction temperature	150			
R _{thja}	Thermal resistance junction-to-ambient ⁽³⁾				°C/W
	SO8	125			
	MiniSO8	190			
	TSSOP8	120			
R _{thjc}	Thermal resistance junction-to-case ⁽³⁾				
	SO8	40			
	MiniSO8	39			
	TSSOP8	37			
ESD	HBM: human body model ⁽⁴⁾	2			kV
	MM: machine model ⁽⁵⁾	200			V
	CDM: charged device model ⁽⁶⁾	1.5			kV

- Short-circuits from the output to V_{CC} can cause excessive heating if $V_{CC} > 15$ V. The maximum output current is approximately 40 mA independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short-circuits on all amplifiers.
- This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V_{CC} voltage level (or to ground for a large overdrive) for the time during which an input is driven negative. This is not destructive and normal output will be restored for input voltage higher than -0.3 V.
- Short-circuits can cause excessive heating and destructive dissipation. R_{th} are typical values.
- Human body model: a 100 pF capacitor is discharged through a 1.5 k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
- Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin combinations with other pins floating.
- Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}^{+}	Supply voltage	3 to 30	V
V_{icm}	Common mode input voltage range ⁽¹⁾	$V_{DD} - 0.3$ to $V_{CC} - 1.5$	
T_{oper}	Operating free air temperature range LM158W LM258W LM358W	-55 to +125 -40 to +105 0 to +70	°C

1. When used in comparator, the functionality is guaranteed as long as at least one input remains within the operating common mode voltage range.

3 Electrical characteristics

Table 3. $V_{CC}^+ = +5\text{ V}$, $V_{CC}^- = \text{ground}$, $V_o = 1.4\text{ V}$, $T_{\text{amb}} = +25\text{ }^\circ\text{C}$
(unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage ⁽¹⁾				
	LM158AW		1	2	
	LM258AW, LM358AW		1	3	
	LM158W, LM258W		2	5	
	LM358W		2	7	mV
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$				
	LM158AW, LM258AW, LM358AW			4	
	LM158W, LM258W			7	
	LM358W			9	
$\Delta V_{io}/\Delta T$	Input offset voltage drift				
	LM158AW, LM258AW, LM358AW		7	15	$\mu\text{V}/^\circ\text{C}$
	LM158W, LM258W, LM358W		7	30	
I_{io}	Input offset current				
	LM158AW, LM258AW, LM358AW		2	10	
	LM158W, LM258W, LM358W		2	30	nA
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$				
	LM158AW, LM258AW, LM358AW			30	
	LM158W, LM258W, LM358W			40	
$\Delta I_{io}/\Delta T$	Input offset current drift				
	LM158AW, LM258AW, LM358AW		10	200	$\text{pA}/^\circ\text{C}$
	LM158W, LM258W, LM358W		10	300	
I_{ib}	Input bias current ⁽²⁾				
	LM158AW, LM258AW, LM358AW		20	50	
	LM158W, LM258W, LM358W		20	150	nA
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$				
	LM158AW, LM258AW, LM358AW			100	
	LM158W, LM258W, LM358W			200	
A_{vd}	Large signal voltage gain				
	$V_{CC}^+ = +15\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_o = 1.4\text{ V}$ to 11.4 V	50	100		V/mV
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$	25			
SVR	Supply voltage rejection ratio				
	$R_s \leq 10\text{ k}\Omega$, $V_{CC}^+ = 5\text{ V}$ to 30 V	65	100		dB
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$	65			
I_{CC}	Supply current, all amp, no load				
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$, $V_{CC}^+ = +5\text{ V}$		0.7	1.2	mA
	$T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$, $V_{CC}^+ = +30\text{ V}$			2	

Table 3. $V_{CC}^+ = +5\text{ V}$, $V_{CC}^- = \text{ground}$, $V_o = 1.4\text{ V}$, $T_{\text{amb}} = +25\text{ }^\circ\text{C}$
(unless otherwise specified) (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{icm}	Input common mode voltage range $V_{CC}^+ = +30\text{ V}^{(3)}$ $T_{\text{amb}} = +25\text{ }^\circ\text{C}$ $T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$	0 0		$V_{CC}^+ - 1.5$ $V_{CC}^+ - 2$	V
CMR	Common mode rejection ratio $R_s \leq 10\text{ k}\Omega$ $T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$	70 60	85		dB
I_{source}	Output current source $V_{CC}^+ = +15\text{ V}$, $V_o = +2\text{ V}$, $V_{\text{id}} = +1\text{ V}$	20	40	60	mA
I_{sink}	Output sink current $V_{CC}^+ = +15\text{ V}$, $V_o = +2\text{ V}$, $V_{\text{id}} = -1\text{ V}$ $V_{CC}^+ = +15\text{ V}$, $V_o = +0.2\text{ V}$, $V_{\text{id}} = -1\text{ V}$	10 12	20 50		mA μA
V_{OH}	High level output voltage $R_L = 2\text{ k}\Omega$, $V_{CC}^+ = 30\text{ V}$ $T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$ $R_L = 10\text{ k}\Omega$, $V_{CC}^+ = 30\text{ V}$ $T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$	26 26 27 27	27 28		V
V_{OL}	Low level output voltage $R_L = 10\text{ k}\Omega$ $T_{\text{min}} \leq T_{\text{amb}} \leq T_{\text{max}}$		5	20 20	mV
SR	Slew rate $V_{CC}^+ = 15\text{ V}$, $V_i = 0.5\text{ to }3\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, unity gain	0.3	0.6		V/ μs
GBP	Gain bandwidth product $V_{CC}^+ = 30\text{ V}$, $f = 100\text{ kHz}$, $V_{\text{in}} = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	0.7	1.1		MHz
THD	Total harmonic distortion $f = 1\text{ kHz}$, $A_v = 20\text{ dB}$, $R_L = 2\text{ k}\Omega$, $V_o = 2\text{ V}_{\text{pp}}$, $C_L = 100\text{ pF}$, $V_o = 2\text{ V}_{\text{pp}}$		0.02		%
e_n	Equivalent input noise voltage $f = 1\text{ kHz}$, $R_s = 100\text{ }\Omega$, $V_{CC}^+ = 30\text{ V}$		55		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
V_{o1}/V_{o2}	Channel separation ⁽⁴⁾ $1\text{ kHz} \leq f \leq 20\text{ kHz}$		120		dB

- $V_o = 1.4\text{ V}$, $R_s = 0\text{ }\Omega$, $5\text{ V} < V_{CC}^+ < 30\text{ V}$, $0 < V_{\text{ic}} < V_{CC}^+ - 1.5\text{ V}$.
- The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so there is no change in the load on the input lines.
- The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3 V . The upper end of the common-mode voltage range is $V_{CC}^+ - 1.5\text{ V}$, but either or both inputs can go to $+32\text{ V}$ without damage.
- Due to the proximity of external components ensure that there is no coupling originating via stray capacitance between these external parts. Typically, this can be detected at higher frequencies because then this type of capacitance increases.

Figure 2. Open loop frequency response

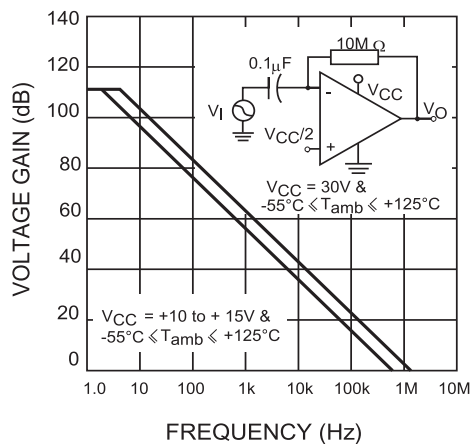


Figure 3. Large signal frequency response

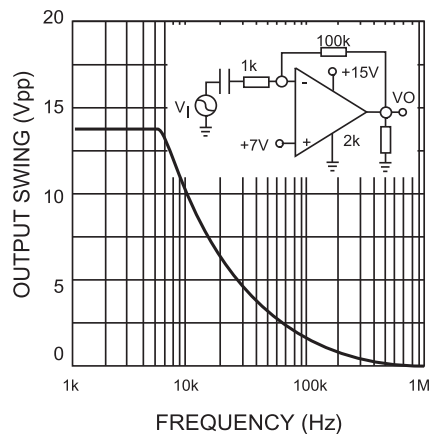


Figure 4. Voltage follower pulse response (large signal)

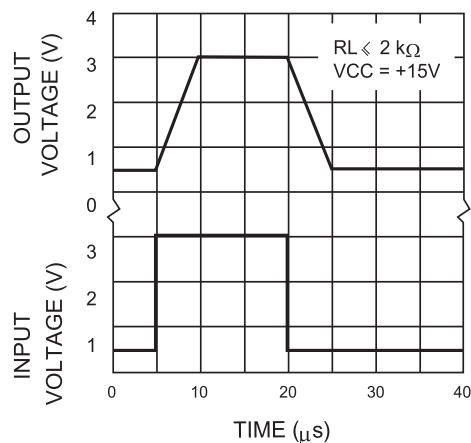


Figure 5. Voltage follower pulse response (small signal)

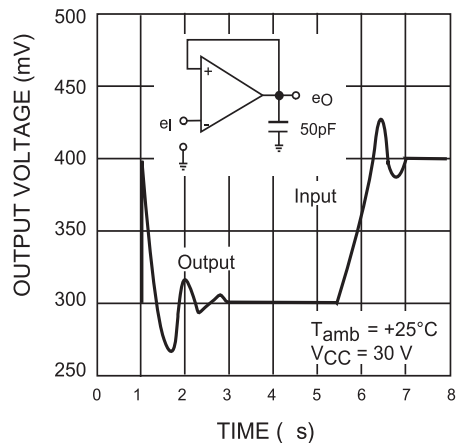


Figure 6. Input bias current vs. temperature

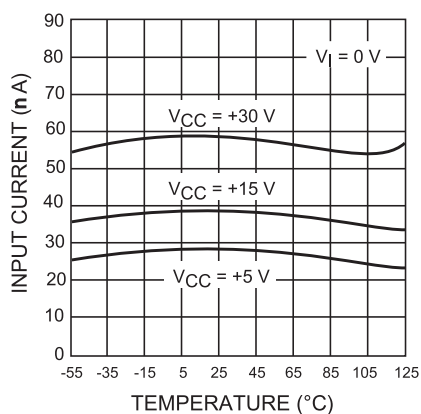


Figure 7. Output characteristics (sink)

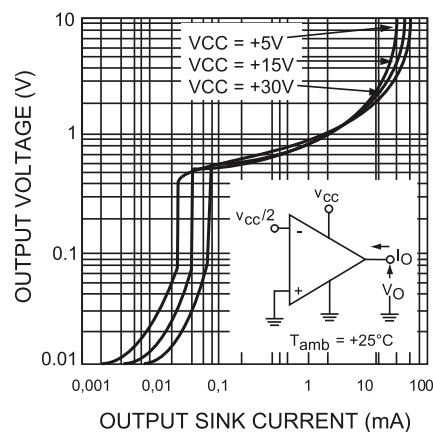


Figure 8. Output characteristics (source)

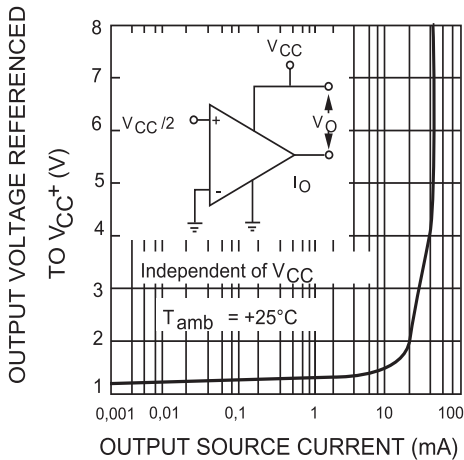


Figure 9. Current limiting

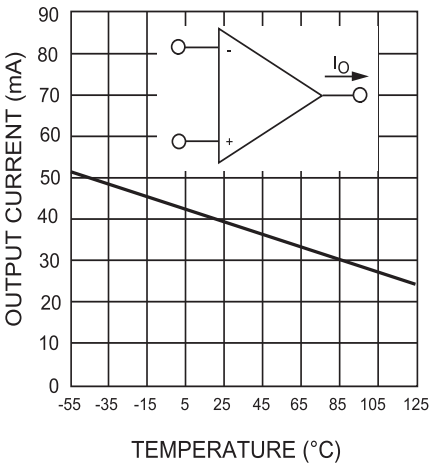


Figure 10. Input voltage range

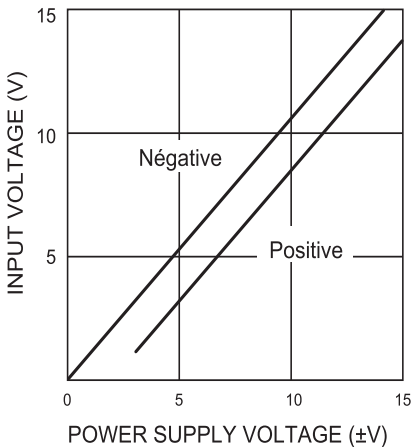


Figure 11. Open loop gain

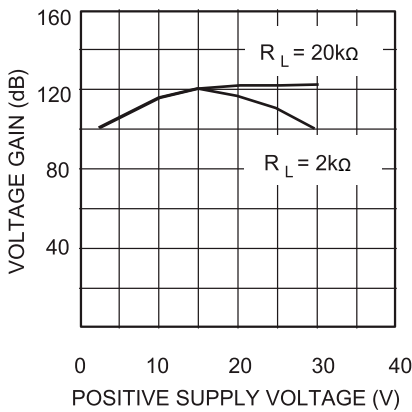


Figure 12. Supply current

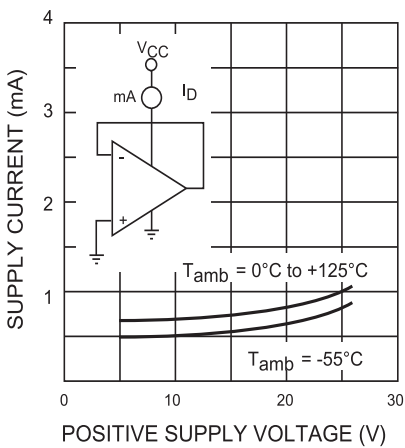


Figure 13. Input bias current vs. positive supply voltage

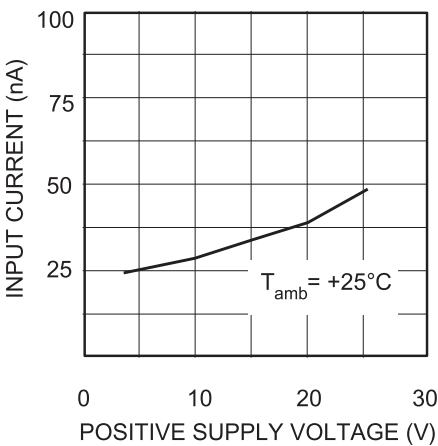


Figure 14. Gain bandwidth product

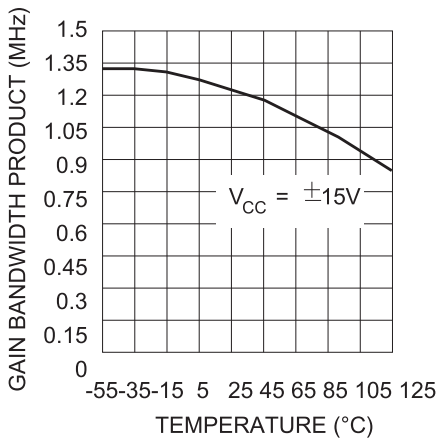


Figure 15. Power supply rejection ratio

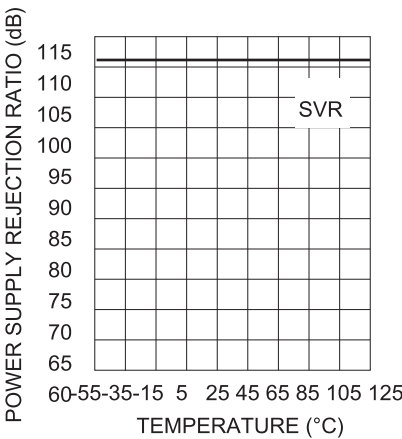


Figure 16. Common mode rejection ratio

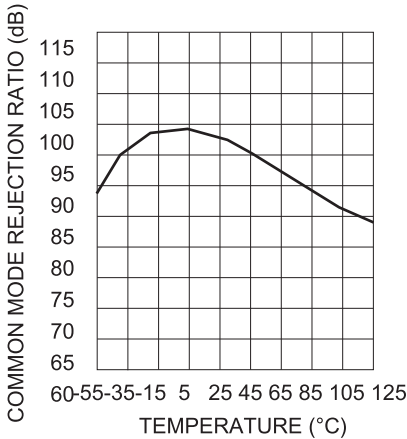
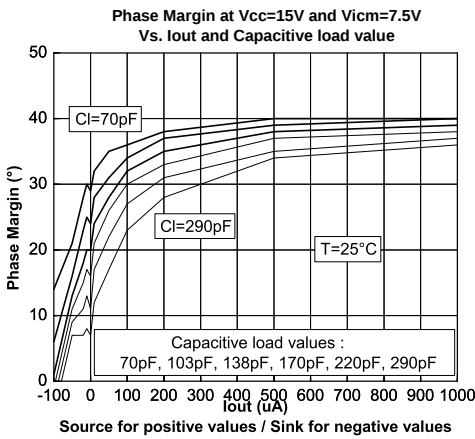


Figure 17. Phase margin vs. capacitive load



4 Typical applications

Single supply voltage $V_{CC} = +5 V_{DC}$

Figure 18. AC-coupled inverting amplifier

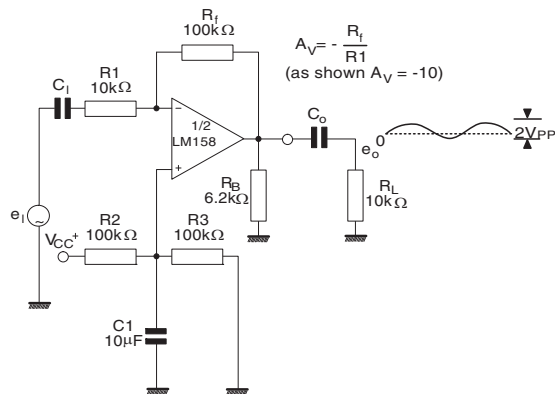


Figure 19. Non-inverting DC amplifier

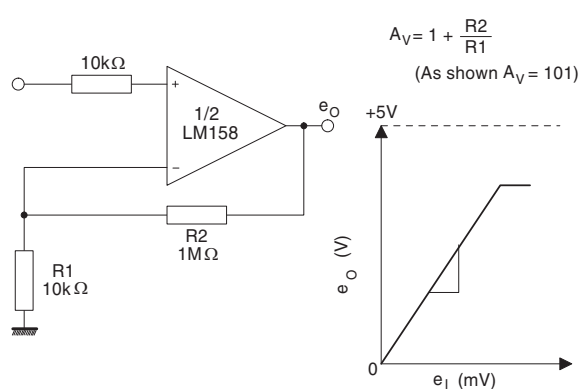


Figure 20. AC-coupled non-inverting amplifier

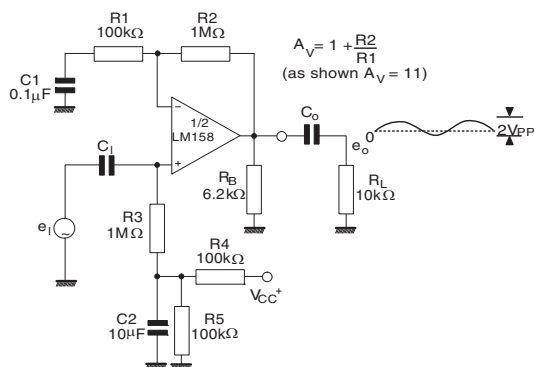


Figure 21. DC summing amplifier

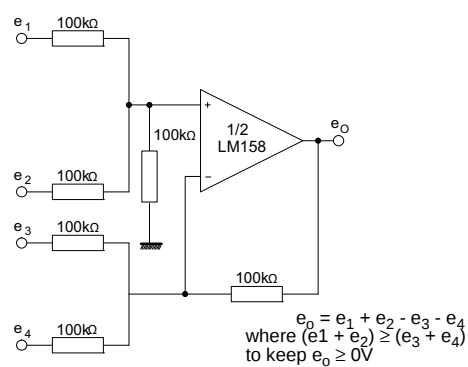


Figure 22. High input Z, DC differential amplifier

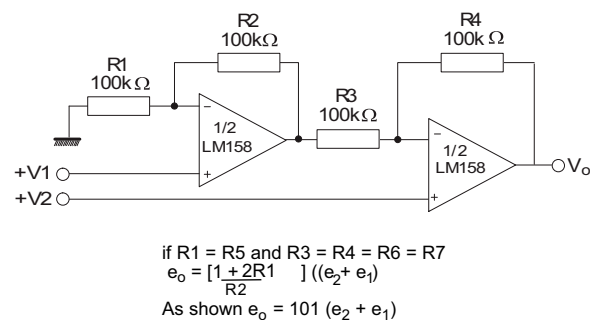


Figure 23. High input Z adjustable gain DC instrumentation amplifier

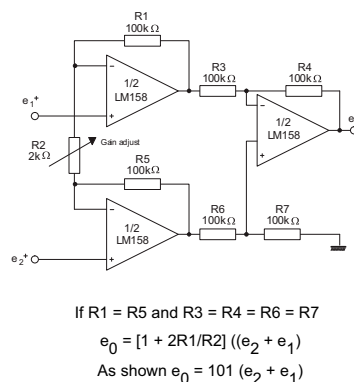


Figure 24. Using symmetrical amplifiers to reduce input current

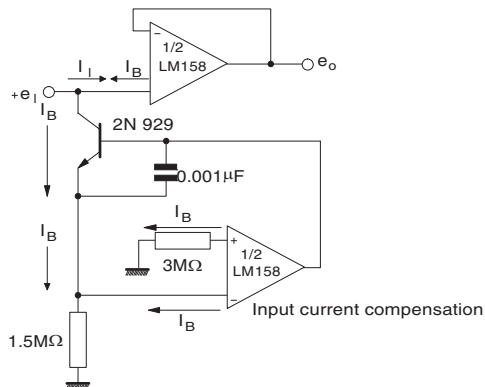


Figure 25. Low drift peak detector

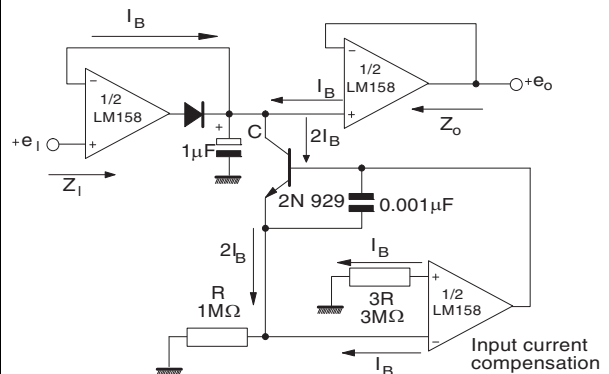
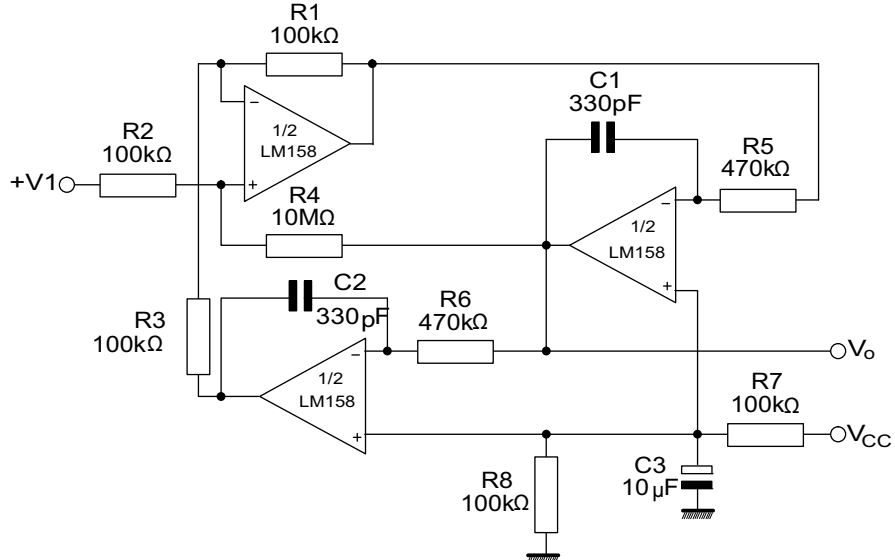


Figure 26. Active band-pass filter



5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

5.1 SO8 package information

Figure 27. SO8 package outline

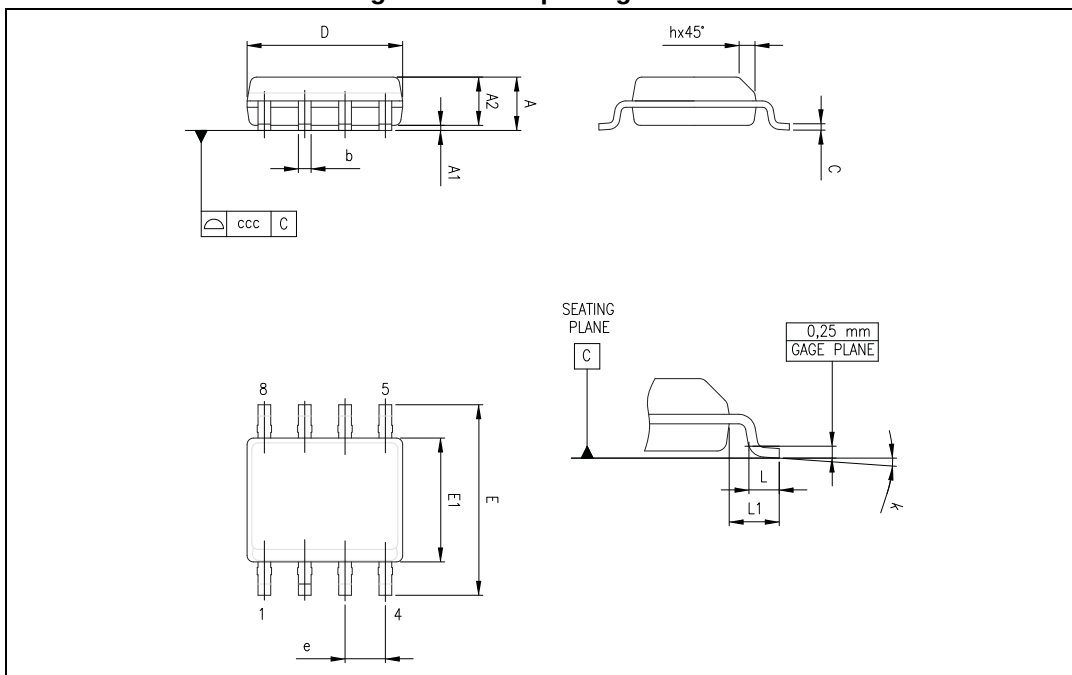


Table 4. SO8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	1 °		8 °	1 °		8 °
ccc			0.10			0.004

5.2 MiniSO8 package information

Figure 28. MiniSO8 package outline

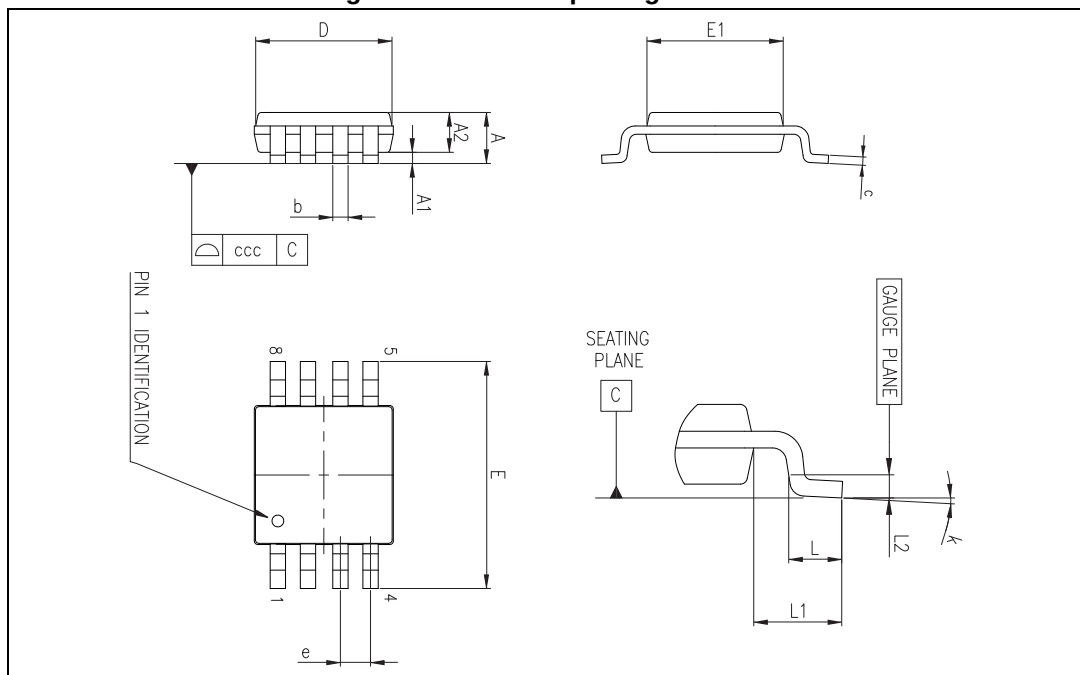


Table 5. MiniSO8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0		0.15	0		0.006
A2	0.75	0.85	0.95	0.030	0.033	0.037
b	0.22		0.40	0.009		0.016
c	0.08		0.23	0.003		0.009
D	2.80	3.00	3.20	0.11	0.118	0.126
E	4.65	4.90	5.15	0.183	0.193	0.203
E1	2.80	3.00	3.10	0.11	0.118	0.122
e		0.65			0.026	
L	0.40	0.60	0.80	0.016	0.024	0.031
L1		0.95			0.037	
L2		0.25			0.010	
k	0 °		8 °	0 °		8 °
ccc			0.10			0.004

5.3 TSSOP8 package information

Figure 29. TSSOP8 package outline

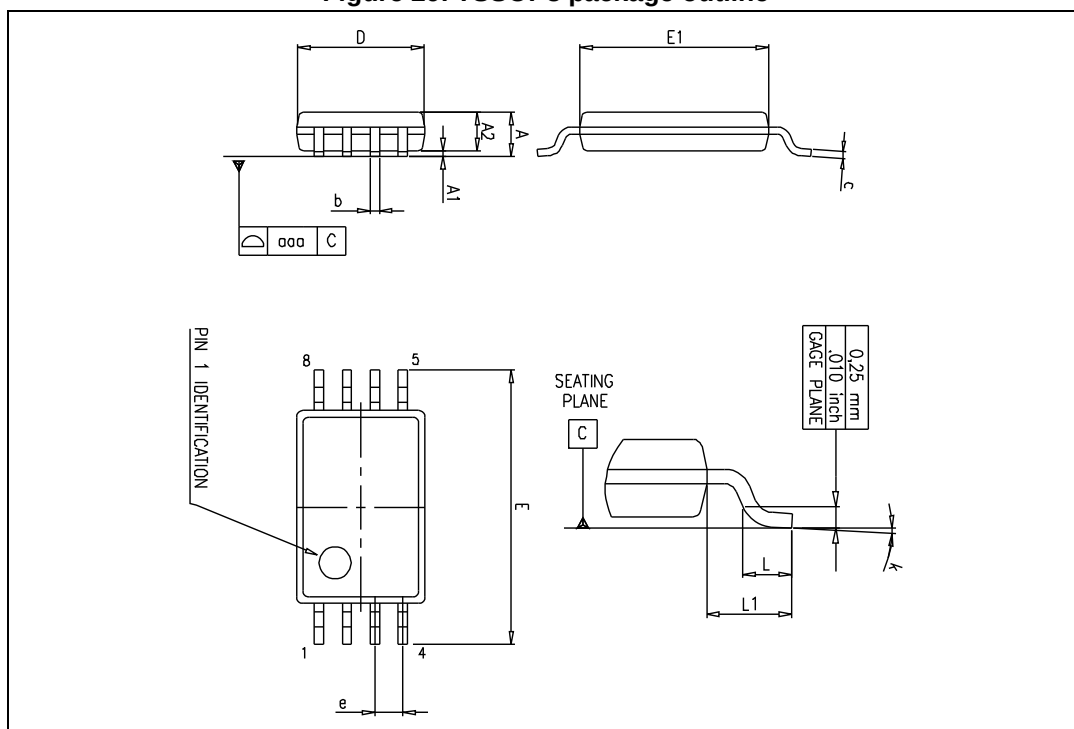


Table 6. TSSOP8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
e		0.65			0.0256	
k	0 °		8 °	0 °		8 °
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa		0.1			0.004	

6 Ordering information

Table 7. Order codes

Order code	Temperature range	Package	Packing	Marking
LM158WDT	-55 °C, +125 °C	SO8	Tape and reel	158W
LM258AWDT	-40 °C, +105 °C			TSSOP8
LM258WDT		258W		
LM258WPT		SO8 (automotive grade)		258W
LM258WYDT ⁽¹⁾		TSSOP8 (automotive grade)		258WY
LM258WYPT				258WY
LM258AWYPT				K410
LM358WST	0 °C, +70 °C	MiniSO8		K417
LM358AWDT		SO8		358AW
LM358AWPT		TSSOP8		
LM358AWST		MiniSO8		K418
LM358WDT		SO8		358W

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent are qualified.

7 Revision history

Table 8. Document revision history

Date	Revision	Changes
01-Nov-2002	1	First release.
01-Jul-2005	2	ESD protection inserted in <i>Table 1: Absolute maximum ratings on page 4</i> .
06-Oct-2006	3	ESD tolerance for model HBM improved to 2kV in <i>Table 1: Absolute maximum ratings on page 4</i> . R_{thja} and R_{thjc} typical values added in <i>Table 1: Absolute maximum ratings on page 4</i> . Added <i>Figure 17: Phase margin vs. capacitive load on page 10</i> .
02-Jan-2007	4	Order codes added (automotive grade level) to <i>Section 6: Ordering information</i> .
15-Mar-2007	5	Previously called revision 4. Footnote for automotive grade order codes added to <i>Section 6: Ordering information</i> .
25-Apr-2007	6	Added missing Revision 4 of January 2007 in revision history. Corrected revision number of March 2007 to Revision 5.
11-Feb-2008	7	Reformatted electrical characteristics table. Reformatted package information. Corrected MiniSO8 package information. Corrected operating temperature range for automotive grade parts.
26-Aug-2008	8	Corrected ESD values in <i>Table 1: Absolute maximum ratings</i> . Added limitations on input current in <i>Table 1: Absolute maximum ratings</i> . Corrected title for <i>Figure 11</i> . Added E and L1 parameters in <i>Table 4: SO8 package mechanical data</i> . Added automotive grade products for MSO8 package in <i>Table 7: Order codes</i> .
03-Jul-2012	9	Automotive grade level updated in <i>Table 7: Order codes</i> . Removed order codes: LM358WYD, LM358AWYD, LM258WYD, LM258AWYD.
09-Jan-2013	10	Small text changes in <i>Features and Description</i> . <i>Figure 1: Schematic diagram (1/2 LM158W/LM258W/LM358W)</i> : replaced. <i>Table 7: Order codes</i> : added order codes LM358WST and LM358AWST.
15-Jul-2013	11	<i>Table 3</i> : replaced DV_{iO} with $\Delta V_{iO}/\Delta T$ and DI_{iO} with $\Delta I_{iO}/\Delta T$ <i>Table 7: Order codes</i> : removed the following order codes: LM158WN, LM158WD, LM258AWYST, LM258WAN, LM258WAD, LM258WD, LM258WYST, LM358WN, LM358WD, LM358AWD, LM358WDT, LM358AWDT, LM358WPT, LM358AWPT, LM358WYDT, LM358AWYDT, LM358AWYPT; updated footnote 1.

Table 8. Document revision history

Date	Revision	Changes
18-Sep-2014	12	Removed DIP8 package <i>Table 7: Order codes:</i> removed the order codes LM258WN, LM258AWYDT, LM258AWPT, LM358AWYST, LM358WYST, and LM358WYPT; added the order codes LM258WYDT, LM358AWDT, LM358AWPT, and LM358WDT.
06-May-2015	13	<i>Section 5: Package information:</i> replaced “package mechanical drawing” with “package outline”. <i>Table 7: Order codes:</i> removed “tube” packaging from all products
31-Jul-2019	14	Updated Table 7: Order codes .

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9